

BT236X-800G

Rev.01 - 25 April 2018

4Q Triac

Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT186A (TO-220F) plastic package intended for use in general purpose bidirectional switching and phase control applications.

2. Features and benefits

- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- · Least sensitive gate for highest noise immunity
- Triggering in all four quadrants
- Isolated package

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating		· · ·				
V_{DRM}	repetitive peak off-state voltage			8	300		V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 88 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	6			A	
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	65			A	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		-	5	50	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>		-	8	50	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>		-	11	50	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _I = 25 °C; <u>Fig. 7</u>		-	30	100	mA

5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2		Ν
3	G	gate		
mb	n.c.	mounting base; isolated		sym051

6. Ordering information

Table 3. Ordering information						
Type number	ber Package					
	Name	Description	Version			
BT236X-800G	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A			

7. Marking

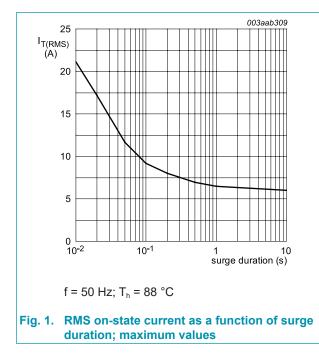
Table 4. Marking codes							
Type number	Marking codes						
BT236X-800G	BT236X-800G						

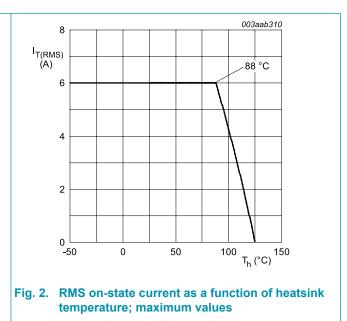
8. Limiting values

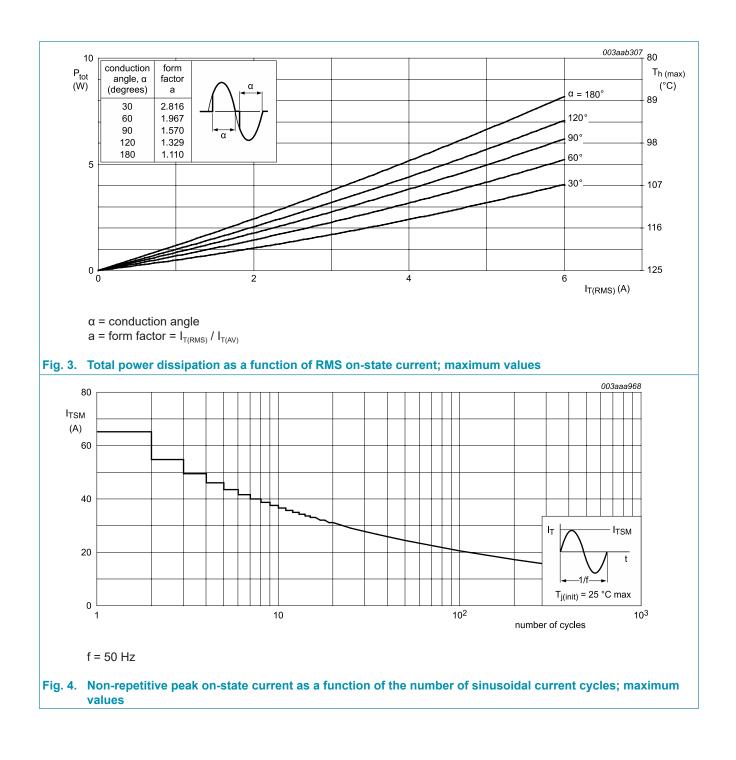
Table 5. Limiting values

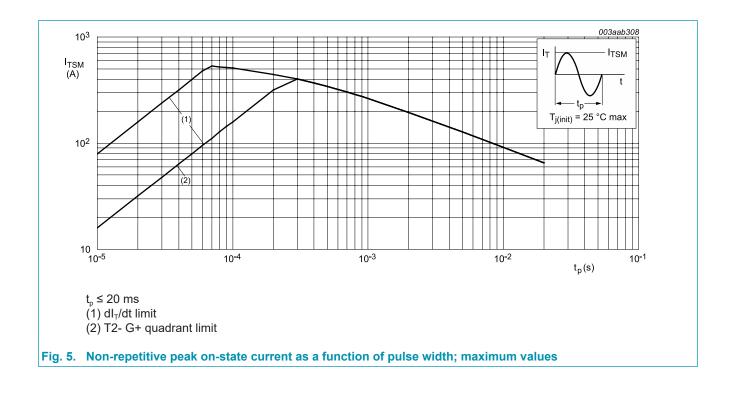
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _h ≤ 88 °C; <u>Fig 1</u> ; <u>Fig 2</u> ; <u>Fig 3</u>	6	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	65	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	71	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	21	A ² s
dI _T /dt	rate of rise of on-state current	I _G = 100 mA; T2+ G+	50	A/µs
		I _G = 100 mA; T2+ G-	50	A/µs
		I _G = 100 mA; T2- G-	50	A/µs
		I _G = 200 mA; T2- G+	10	A/µs
I _{GM}	peak gate current		2	Α
P _{GM}	peak gate power		5	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C



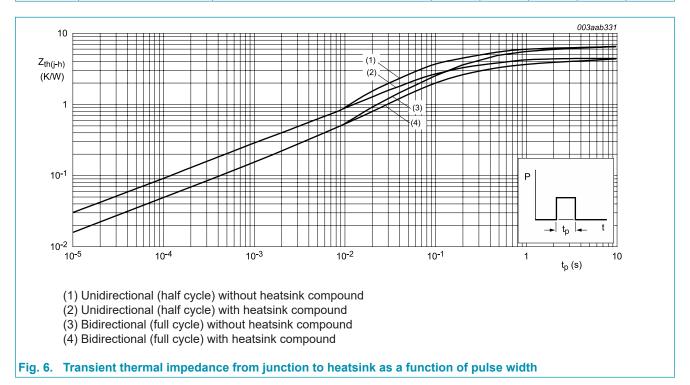






9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	full or half cycle; with heatsink compound; Fig 6	-	-	4.5	K/W
		full or half cycle; without heatsink compound; Fig 6	-	-	6.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

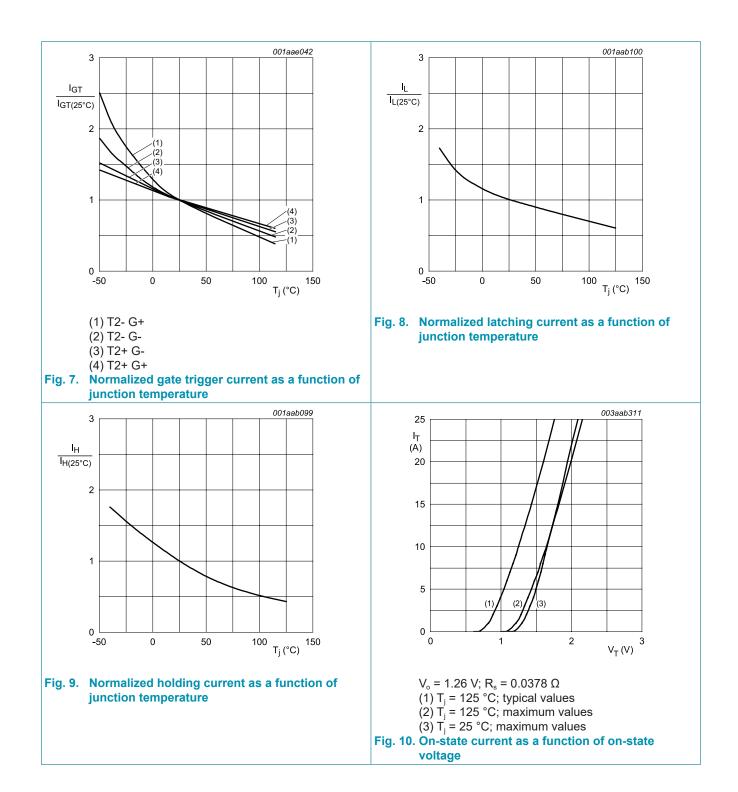


10. Isolation characteristics

Table 7. Isc	olation characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C_{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T_h = 25 °C	-	10	-	pF

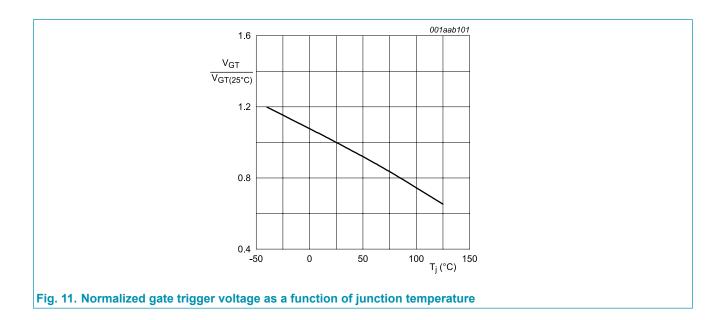
11. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	5	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	8	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7	-	11	50	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; Fig. 7	-	30	100	mA
l	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_j = 25 \text{ °C}; \text{ Fig. 8}$	-	7	45	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 8	-	16	60	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	5	45	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 8	-	7	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	5	40	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.65	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		$V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 125 \text{ °C};$ Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	· · ·	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	200	250	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 95 \text{ °C}; \text{ I}_T = 6 \text{ A};$ $dI_{com}/dt = 3.6 \text{ A/ms}; \text{ gate open circuit}$	10	20	-	V/µs
t _{gt}	gate-controlled turn-on time	$V_{\rm D}$ = 800 V; I _{TM} = 12 A; I _G = 0.1 A; dI _G /dt = 5 A/µs	-	2	-	μs
		1	1			-

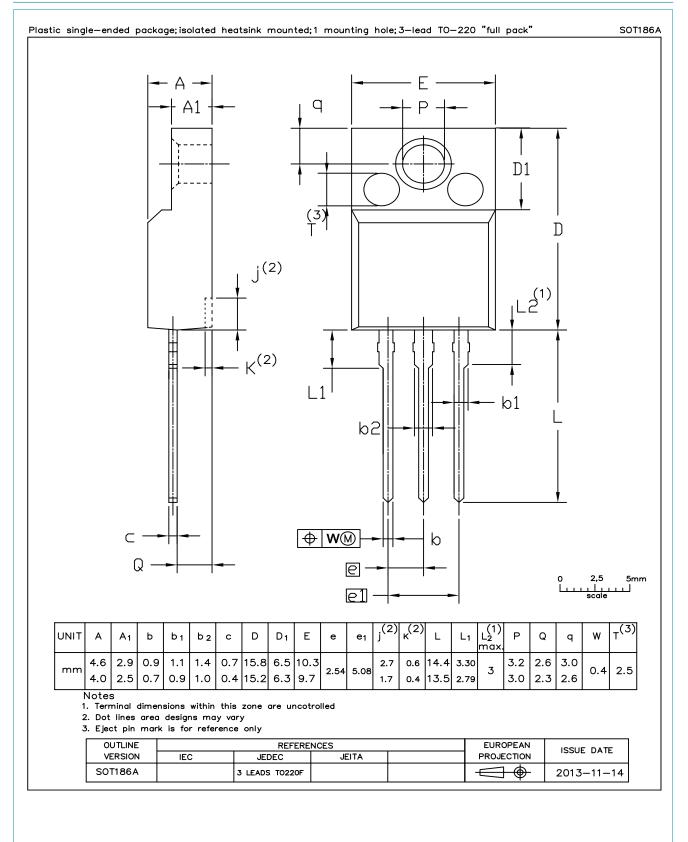


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12. Package outline



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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